

September 2001 Revised February 2002

74ALVCH162374

Low Voltage 16-Bit D-Type Flip-Flop with Bushold and 26 Ω Series Resistors in Outputs

General Description

The ALVCH162374 contains sixteen non-inverting D-type flip-flops with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. A buffered clock (CP) and output enable $(\overline{\text{OE}})$ are common to each byte and can be shorted together for full 16-bit operation

The ALVCH162374 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74ALVCH162374 is also designed with 26Ω series resistors in the outputs. This design reduces line noise in applications such as memory address drivers, clock drivers and bus transceivers/transmitters.

The 74ALVCH162374 is designed for low voltage (1.65V to 3.6V) $\rm V_{CC}$ applications with output compatibility up to 3.6V.

The 74ALVCH162374 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V to 3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold data inputs eliminates the need for external pull-up/pull-down resistors
- \blacksquare 26 Ω series resistors in outputs
- t_{PD} (CLK to O_n)
 - 4.6 ns max for 3.0V to 3.6V $V_{\rm CC}$
 - 5.4 ns max for 2.3V to 2.7V V_{CC}
 - 9.6 ns max for 1.65V to 1.95V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up conforms to JEDEC JED78
- ESD performance:

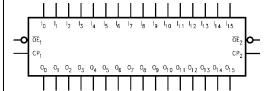
Human body model > 2000V Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Descriptions	
74ALVCH162374T	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide	

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
OE _n	Output Enable Input (Active LOW)
CP _n	Clock Pulse Input
I ₀ -I ₁₅	Bushold Inputs
O ₀ -O ₁₅	Outputs

Connection Diagram

0E ₁ —	l.	\cup	48	— CP1
	l'.		47	
o ₀ —	2			— _{1₀}
01 —	3		46	ا <u>-</u> ا
GND -	4		45	— GNE
02 -	5		44	— I ₂
03 -	6		43	— I ₃
v _{cc} -	7		42	— v _{cc}
04 -	8		41	— I₄
05 -	9		40	— I ₅
GND -	10		39	— GND
o ₆ —	11		38	— I ₆
07 —	12		37	— I ₇
08 —	13		36	— I ₈
o ₉ —	14		35	وا 🗕
GND -	15		34	— GND
010 -	16		33	- I ₁₀
011 -	17		32	— ا _{ا ۱}
v _{cc} —	18		31	- v _{cc}
012 -	19		30	- I ₁₂
013 —	20		29	— I _{1 3}
GND —	21		28	— GNE
014 —	22		27	— I₁₄
015 -	23		26	— I ₁₅
OE ₂	24		25	- CP2
-				ĺ

Truth Tables

	Inputs		Outputs
CP ₁	OE ₁	l ₀ –l ₇	00-07
/	L	Н	Н
~	L	L	L
L	L	Х	O ₀
X	Н	Х	Z

	Inputs		Outputs
CP ₂	OE ₂	I ₈ -I ₁₅	O ₈ -O ₁₅
~	L	Н	Н
~	L	L	L
L	L	Х	O ₀
Х	Н	Х	Z

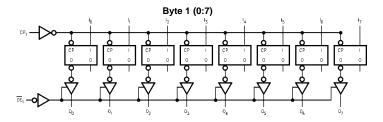
- H = HIGH Voltage Level
- L = LOW Voltage Level
 X = Immaterial (HIGH or LOW, control inputs may not float)
 Z = High Impedance
- $O_0 = Previous O_0$ before HIGH-to-LOW of CP

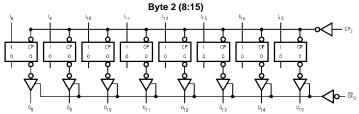
Functional Description

The 74ALVCH162374 consists of sixteen edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. Each clock has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each

flip-flop will store the state of their individual I inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable (\overline{OE}_n) LOW, the contents of the flip-flops are available at the outputs. When $\overline{\text{OE}}_n$ is HIGH, the outputs go to the high impedance state. Operations of the $\overline{\text{OE}}_{\text{n}}$ input does not affect the state of the flip-flops.

Logic Diagram





Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

 $\begin{tabular}{lll} Supply Voltage (V_{CC}) & -0.5V to +4.6V \\ DC Input Voltage (V_I) & -0.5V to 4.6V \\ \end{tabular}$

Output Voltage (V $_{\rm O}$) (Note 2) $-0.5 \mbox{V}$ to V $_{\rm CC}$ +0.5 \mathbf{V}

DC Input Diode Current (I_{IK})

 $V_1 < 0V$ -50 mA

DC Output Diode Current (I_{OK})

 $V_O < 0V$ –50 mA

DC Output Source/Sink Current
(I_{OH}/I_{OL})

DC V_{CC} or GND Current per

Supply Pin (I_{CC} or GND) ±100 mA

Storage Temperature Range (T_{STG}) $-65^{\circ}C$ to $+150^{\circ}C$

Recommended Operating Conditions (Note 3)

Power Supply

±50 mA

Operating 1.65V to 3.6V Input Voltage (V_I) 0V to V_{CC}

Minimum Input Edge Rate (Δt/ΔV)

 $V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$ 10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: $I_{\rm O}$ Absolute Maximum Rating must be observed, limited to 4.6V. Note 3: Floating or unused control inputs must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		1.65 - 1.95	0.65 x V _{CC}		
			2.3 - 2.7	1.7		V
			2.7 - 3.6	2.0		
V _{IL}	LOW Level Input Voltage		1.65 - 1.95		0.35 x V _{CC}	
			2.3 - 2.7		0.7	V
			2.7 - 3.6		8.0	
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	1.65 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.65	1.2		
		I _{OH} = -4 mA	2.3	1.9		
		$I_{OH} = -6 \text{ mA}$	2.3	1.7		V
			3.0	2.4		
		$I_{OH} = -8 \text{ mA}$	2.7	2		
		$I_{OH} = -12 \text{ mA}$	3.0	2		
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	1.65 - 3.6		0.2	
		I _{OL} = 2 mA	1.65		0.45	
		I _{OL} = 4 mA	2.3		0.4	
		I _{OL} = 6 mA	2.3		0.55	V
			3.0		0.55	
		I _{OL} = 8 mA	2.7		0.6	
		I _{OL} = 12 mA	3		0.8	
l _l	Input Leakage Current	$0 \le V_1 \le 3.6V$	3.6		±5.0	μΑ
I _{I(HOLD)}	Bushold Input Minimum	V _{IN} = 0.58V	1.65	25		
	Drive Hold Current	$V_{IN} = 1.07V$	1.65	-25		
		$V_{IN} = 0.7V$	2.3	45		
		V _{IN} = 1.7V	2.3	-45		μΑ
		$V_{IN} = 0.8V$	3.0	75		
		$V_{IN} = 2.0V$	3.0	-75		
		$0 < V_O \le 3.6V$	3.6		±500	
l _{oz}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	3.6		±10	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6		40	μΑ
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	3 - 3.6		750	μΑ

AC Electrical Characteristics

		$T_A = -40$ °C to $+85$ °C, $R_L = 500\Omega$								
Symbol	Parameter	C _L = 50 pF			C _L = 30 pF			Units		
Зупівої		$V_{CC} = 3.3V \pm 0.3V$		V _{CC} = 2.7V V _C		V _{CC} = 2.	$\text{V}_{\text{CC}} = \text{2.5V} \pm \text{0.2V}$		$V_{CC} = 1.8V \pm 0.15V$	
		Min	Max	Min	Max	Min	Max	Min	Max	
f _{CLOCK}	Clock Frequency		150		150		150		100	MHz
t _W	Pulse Width	3.3		3.3		3.3		4.0		ns
t _S	Setup Time	1.9		2.2		2.1		2.5		ns
t _H	Hold Time	0.5		0.5		0.6		1.0		ns
f _{MAX}	Maximum Clock Frequency	150		150		150		100		MHz
t _{PHL} , t _{PLH}	Propagation Delay	1.0	4.6		5.4	1.0	5.4	1.5	9.6	ns
t_{PZL}, t_{PZH}	Output Enable Time	1.0	5.2		6.4	1.0	6.5	1.5	9.8	ns
t _{PLZ} , t _{PHZ}	Output Disable Time	1.2	4.5		5	1.0	5.6	1.5	7.9	ns

Capacitance

Symbol	Symbol Parameter		Conditions	T _A = -	Units		
Syllibol			Conditions	v _{cc}	Typical	Oilles	
C _{IN}	Input Capacitance	Control	$V_I = 0V$ or V_{CC}	3.3	3		
		Data	$V_I = 0V$ or V_{CC}	3.3	6	pF	
C _{OUT}	Output Capacitance		V _I = 0V or V _{CC}	3.3	7	pF	
C _{PD}	Power Dissipation Capacitance	Outputs Enabled	f = 10 MHz, C _L = 0 pF	3.3	31		
				2.5	28	pF	
		Outputs Disabled	f = 10 MHz, C _L = 0 pF	3.3	11	ρi	
				2.5	10		

AC Loading and Waveforms

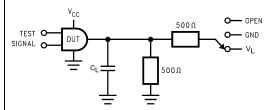


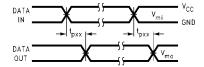
TABLE 1. Values for Figure 1

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t_{PZL}, t_{PLZ}	V _L
t_{PZH},t_{PHZ}	GND

FIGURE 1. AC Test Circuit

TABLE 2. Variable Matrix (Input Characteristics: f= 1MHz; $t_r=t_f=$ 2ns; $Z_0=50\Omega)$

Symbol	V _{CC}							
	3.3V ± 0.3V	2.7V	2.5V ± 0.2V	1.8V ± 0.15V				
V _{mi}	1.5V	1.5V	V _{CC} /2	V _{CC} /2				
V _{mo}	1.5V	1.5V	V _{CC} /2	V _{CC} /2				
V _X	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V				
V _Y	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V				
V_{L}	6V	6V	V _{CC} *2	V _{CC} *2				



OUTPUT CONTROL TPZH TPHZ Vmi GNE Vcc GNE Vmi GNE Vmi GNE Vcc GNE Vcc GNE Vmi GNE Vcc G

FIGURE 2. Waveform for Inverting and Non-Inverting Functions

FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

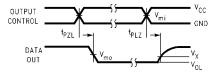


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

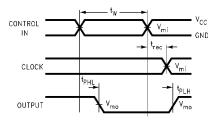


FIGURE 5. Propagation Delay, Pulse Width and $$t_{\mbox{\scriptsize REC}}$$ Waveforms

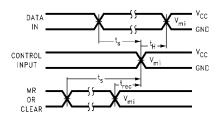
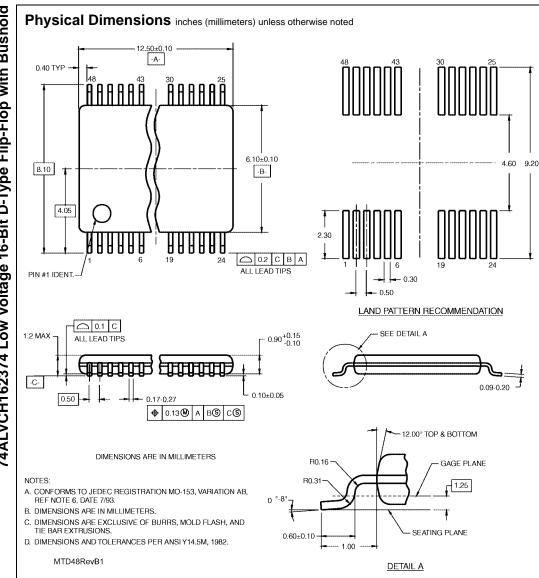


FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Body Width Package Number MTD48

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